NSN 5961-01-233-0780

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-233-0780 **Inclosure Material:** Metal **Overall Length:** 0.357 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.235 inches **Function For Which Designed:** Transient suppressor Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-13 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 77.8 working peak reverse voltage and 86.5 breakdown voltage, dc and 95.5 breakdown voltage, dc **Current Rating Per Characteristic:** 200.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/500 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Mil-std (military Standard):

Mil-prf-19500 spec.

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